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FACIMILE TRANSMISSION COVER SHEET

To: Honorable Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

☑ In re application of:

Appl. No.:

10/619,978

Applicants:

Yong-Bae Kim and Philippe Schoenborn

Filed:

July 14, 2003

TC./A.U.:

1765

Examiner:

Kin-Chan Chen

Title:

PROCESS FOR REMOVAL OF PHOTORESIST MASK USED FOR MAKING VIAS IN LOW K CARBON-DOPED SILICON OXIDE DIELECTRIC MATERIAL, AND FOR REMOVAL OF ETCH RESIDUES FROM FORMATION OF VIAS AND

REMOVAL OF PHOTORESIST MASK

Docket No.:

01-125/1C

I hereby certify that the accompanying amendment is being facsimile transmitted to the Patent and Trademark Office (Fax No. (703) 872-9308)) on the date shown below; on	CERTIFICATION OF FACSIMILE TRANSMISSION					
(Date of Facsimile Transmission) John P. Taylor, Reg. No. 22,369 F. Jourge Signature May 23, 2005						
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Signature May 23, 2005	John P. Taylor, Reg. No. 22,369					
May 23, 2005	July P. Jays					
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Total Pages (including this cover sheet):

16

Documents included:

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1 Pages

Amendment Transmittal Letter

2 Pages

Amendment

11 Pages

Terminal Disclaimer

2 Pages

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* Received: 2 pages. CH

AMENDMENT TRANSMITTAL LETTER			ATTORNEY'S DOCKET NO. 01-125/1C	
SERIAL NO. 10/619,978	FILING DATE July 14, 2003	EXAMINER Kin-Chan Chen		GROUP ART UNIT 1765

INVENTION

PROCESS FOR REMOVAL OF PHOTORESIST MASK USED FOR MAKING VIAS IN LOW K CARBON-DOPED SILICON OXIDE DIELECTRIC MATERIAL, AND FOR REMOVAL OF FICH RESIDUES FROM FORMATION OF VIAS AND REMOVAL OF PHOTORESIST